Morphology of copper nanoparticles in a nitrogen atmosphere: A first-principles investigation

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We perform first-principles density-functional-theory calculations to determine the stability and associated physical and electronic properties of different adsorption phases of N on Cu (100) and Cu (110) substrates for coverages ranging from 0.125 to 1 monolayer (ML). For N on Cu (100), we consider adsorption in fourfold hollow sites while for N on Cu (110), we consider various adsorption sites including N-induced missing-row surface reconstructions and the surface nitridelike, "pseudo-(100)" reconstruction. We report the atomic and electronic structure and compare with analogous results for N/Cu (111). By combining results from our previous study of the N/Cu (111) system with the current investigations, we predict the possible morphology of a Cu crystal in different nitrogen environments by performing a Wulff construction at appropriate chemical potentials of nitrogen. We also find that all low-energy N/Cu surface structures—namely, Cu (100)-(2 × 2)-N and the surface nitrides found on Cu (110) and Cu (111)—share a common geometric feature: i.e., surface nanopatterns resembling 1 atomic layer of Cu3N (100). These nanopatterned structures exist for a narrow range of nitrogen chemical potentials before the onset of bulk Cu3N, unless kinetically hindered. This qualitative behavior of the predicted formation of thin-surface nitridelike structures prior to the bulk nitride material is very similar to that for transition-metal surfaces in an oxygen atmosphere, where surface oxidelike structures are predicted to be thermodynamically stable prior to bulk oxide formation.

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I. INTRODUCTION

Understanding the interaction between N and Cu surfaces is important as copper-based catalysts are widely used in systems containing nitrogen—for example, the reduction and decomposition of nitrogen oxides1–3 and the oxydehydrogenation (i.e., oxidation) of ammonia.4,5 With regard to the oxidation of ammonia, NH3, it has been proposed that copper oxide is not the active material as had been reported earlier,5 but copper nitride or a mixed Cu3N/Cu2O structure.4 Furthermore, N-modified Cu (100), Cu (110), and Cu (111) surfaces have been used in the nanostructure fabrication of Ag nanowires and Co nanowires and nanodots,6–9 often acting as a template for well-controlled patterned growth of these low-dimensional metallic structures.

These applications have motivated a number of experimental studies of nitrogen adsorption on low-index copper surfaces. Under ambient temperatures and pressures, molecular nitrogen does not interact with Cu surfaces, due to the strong nitrogen-nitrogen bond, so the adsorption of nitrogen on Cu (100), Cu (110), and Cu (111) surfaces has been achieved typically by nitrogen-ion bombardment.10–12 These experimental investigations have resulted in a number of observed adsorption phases, from simple chemisorption to complex surface nitride structures, which have a thickness on the nanometer or subnanometer scale.13

For the N/Cu (100) system, both experimental6–9,12,14–16 and density-functional theory17,18 (DFT) studies have confirmed that N chemisorbs on Cu (100) in the fourfold hollow (4FH) sites, forming a Cu (100)-p(2 × 2)-2N structure, otherwise (and hereafter) known as the Cu (100)-c(2 × 2)-N phase, with 0.5 monolayer (ML) coverage at saturation [see Fig. 1(b)]. In Fig. 1(a), we also show a lower-coverage p(2 × 2)-N (0.25-ML) structure. Interestingly, for nitrogen coverages ΘN in the range of ~0.25–0.5 ML, experimentally it is found that nitrogen induces the formation of periodic, square “nano-grid”-like islands (typically 5 nm × 5 nm), where the local atomic structure of these nano-islands is identical to the Cu (100)-c(2 × 2)-N structure.6–9,12,14–22 To our knowledge, this is the only ordered phase that has been reported for the N/Cu (100) system and it is found to be stable up to 600 K.6–9

From a theoretical point of view, a recent DFT study on the atomic structure and energetics of this experimentally observed Cu (100)-c(2 × 2)-N structure has been performed using the projector-augmented-wave (PAW) method and the generalized gradient approximation (GGA).17 They investigated three different adsorption models: namely, (i) with N at the 4FH site, (ii) with N still at the 4FH site but alternate rows of surface Cu atoms displaced (out of plane) in the direction away from the surface (we refer the reader to Ref. 17 for details), and (iii) with N at the top site. It was found that the most stable absorption phase consists of nitrogen atoms positioned in the 4FH site (i.e., the first model described above), with an adsorption energy of 4.88 eV per nitrogen atom, giving support to experimental observation.

In an earlier DFT-GGA plane-wave pseudopotential study,18 Yoshimoto and Tsuneyuki investigated the formation of these interesting self-organizing surface structures, attempting to understand the driving force behind their stability. They found the surface nitrogen adatom interaction on the Cu (100) surface is attractive, leading to the formation of these c(2 × 2)-N nanoislands as suggested experimentally. In addition, they also studied the diffusion pathways of N on Cu (100) and found the diffusion barrier for N via the bridge site to be 1.5–1.7 eV. Scanning tunneling microscopy (STM) images of the Cu (100)-c(2 × 2)-N structure were simulated and are in line with experimental STM images where bright
FIG. 1. (Color online) Atomic geometries of various N/Cu surface structures: (a) and (b) show the top view of Cu (100)-p(2 × 2)-N and Cu (100)-c(2 × 2)-N, respectively, and that of Cu (110)-p(2 × 3)-2N and Cu (110)-p(2 × 3)-N are depicted in (c) and (d), respectively. For Cu (110)-p(2 × 3)-4N, the top and side views are shown in (e) and (f). Top views of (g) the “16” structure, (i) the “4” structure for one Cu-layer reconstruction (i.e., 1L-“4”), and (k) the “4” structure for the two Cu-layer reconstruction (i.e., 2L-“4”) [with the second-layer Cu atoms highlighted as large dark (red) spheres], (h), (j), and (l) show the corresponding side views of these structures. In all figures lighter large (green) spheres represent top-layer Cu atoms (i.e., Cu_{1l}), darker large (red) spheres represent second-layer Cu atoms (i.e., Cu_{2l}), and dark small (blue) spheres represent N atoms, with the exception in (e) and (f) where the lighter (green) and darker (red) large spheres are used to differentiate the slight rumping seen in the surface nitride layer. The Cu substrate atoms are shown in pale (gray) large spheres. Note that in (g)–(l), the top reconstructed Cu layer is shown in smaller darker (green) spheres for clarity.

features of the Cu (100)-c(2 × 2)-N structure corresponded to N adatoms.

Concerning nitrogen adsorption on Cu (110), early low-energy electron diffraction (LEED) studies find a Cu (110)-p(2 × 3)-4N surface nitridelike structure forms over the substrate, consisting of an almost square Cu (100)-c(2 × 2)-N mesh. This structure has a nitrogen coverage of 0.66 ML and is shown in Figs. 1(e) and 1(f). The Cu (110)-p(2 × 3)-4N structure is structurally reconstructed and geometrically different from simple chemisorbed phases. For this work, it will be referred to as a surface nitride.

Other surface reconstruction models have been proposed in the literature for the (2 × 3) phase, including a “[001] missing-row structure,” which we will refer to hereafter as the “Cu (110)-p(2 × 3)-2N” model, and a “[110] missing-row structure,” which we will refer to hereafter as the “Cu (110)-p(2 × 3)-N” model. Cu (110)-p(2 × 3)-2N is shown in Fig. 1(c), with a top layer Cu row in the [001] direction missing and two nitrogen atoms adsorbed in the long-bridge (LB) site, resulting in a coverage of 0.33 ML. For the Cu (110)-p(2 × 3)-N model, a row of Cu atoms in the [110] direction is removed from the Cu (110) surface, with a nitrogen atom adsorbed in the LB site, resulting in a coverage of 0.17 ML. This structure is shown in Fig. 1(d). To our knowledge, other than the p(2 × 3) phase, no other ordered surface structures have been reported for N/Cu (110).

To date, there have also been no first-principles investigations performed for N/Cu (110).

With regard to nitrogen adsorption on Cu (111), experimental evidence shows that a surface nitride structure forms. This surface nitride is proposed to consist of nitrogen atoms adsorbed in the fourfold hollow sites of a pseudo-(100) reconstruction of the Cu (111) surface with a c(2 × 2) periodicity, i.e., a Cu (100)-c(2 × 2)-N-like mesh forms over the Cu (111) substrate. A STM study has proposed that the above-mentioned pseudo-(100) phase on Cu (111) forms a (25 × 7√3) rectangular commensurate layer on the substrate.

Our recent DFT study of nitrogen adsorption on Cu (111) (Ref. 39) is consistent with experimental results finding models of the pseudo-(100) reconstruction to be both energetically preferred over other adsorption structures considered, such as on-surface adsorption at fcc or hcp threefold hollow sites, as well as subsurface adsorption. The most favorable model of the surface nitride reconstruction that we considered consisted of a (2 × 3) surface unit cell, which will be referred to as the “16” structure [see Figs. 1(g) and 1(h)], since the area of this cell is 16 times larger than that of the primitive Cu (111) unit cell. In addition, we also investigated surface nitride structures with a smaller periodicity: namely, the “4” structure—one with only the outermost layer of Cu atoms reconstructed, 1L-“4” [Figs. 1(i) and 1(j)] and another with the two outermost Cu layers reconstructed, 2L-“4” [Figs. 1(k) and 1(l)]. These structures have 4 times the area of the primitive Cu (111) unit cell and are energetically less favorable than the “16” structure. Further details can be found in Ref. 39.

In the present work we present a DFT study of the chemisorbed phases of nitrogen on Cu (100) and Cu (110) surfaces, where we consider coverages ranging from 0.125 to 1 ML. For the N/Cu (110) system, we include surface reconstructions involving missing Cu rows in the [110] and [001] directions—i.e., the Cu (110)-p(2 × 3)-N and Cu (110)-p(2 × 3)-2N structures, respectively, as well as a reconstructed Cu (110)-p(2 × 3)-4N surface nitridelike structure. Finally, chemisorption structures with N in the 4FH, 3FH (i.e., pseudo-threefold-hollow), (LB), and short bridge (SB) sites, on both the ideal Cu (110) surface and that with a row of Cu atoms missing in the [110] direction, are considered. For Cu (100), only the most favorable 4FH site is investigated. For all structures, we examine the electronic properties, atomic geometries, and their relative energetic stabilities. The findings for the N/Cu (100) and N/Cu (110) structures are compared with the results of our previous study of nitrogen adsorption on Cu (111).
possible “nanomorphology” of Cu particles under various nitrogen atmospheres. In particular, having obtained accurate DFT-derived surface energies of these N/Cu low-index surface structures, we perform a Wulff construction\textsuperscript{39} at selected values of the nitrogen-atom chemical potential and explore how the Wulff polygon changes from nitrogen-lean to nitrogen-rich conditions.

II. METHODOLOGY

The DFT calculations are performed with the DMol\textsuperscript{3} code, using the generalized gradient approximation (GGA) for the exchange-correlation functional due to Perdew, Burke, and Ernzerhof (PBE).\textsuperscript{41} DMol\textsuperscript{3} is a numerical implementation which uses a highly efficient local orbital basis set. Further details about the code can be found elsewhere.\textsuperscript{42,43}

The Cu (100) substrate is modeled using a supercell, with nitrogen coverage on both sides of a 9-atomic-layer slab, while the Cu (110) substrate is modeled with 11 atomic layers, preserving inversion symmetry in both surface models. The vacuum region between repeated slabs is 30 Å. The double-$\zeta$ plus polarization (DNP) basis set and a real space cutoff of 9 bohrs are used for all calculations. Brillouin-zone integrations are performed using a $(12 \times 12 \times 1)$ Monkhorst-Pack grid for the Cu (100) $(1 \times 1)$ surface unit cell, and equivalent $k$-point sampling is used for the larger cells. For the Cu (110) surface, a $(12 \times 6 \times 1)$ grid is used for the $(1 \times 1)$ surface unit cell and equivalent sampling for larger cells—for example, a $(6 \times 2 \times 1)$ grid for the $(2 \times 3)$ surface cell. For all calculations, the inner three atomic layers of each slab are fixed and all other atoms are relaxed until the forces are less than 0.3 mHa/bohr (0.015 eV/Å). These parameters were chosen to ensure that calculated energies are well converged, with an estimated numerical uncertainty of less than 1 mHa (see the Appendix).

The calculated average binding energies with respect to the free nitrogen atom (per N atom) are presented in Fig. 2. The binding energy is calculated according the formula

$$E_b^N = -\frac{1}{N_N}(E_{N/Cu} - E_{Cu}^{slab} - \Delta N_{Cu} E_{Cu} - N_N E_N),$$

where $N_N$ and $\Delta N_{Cu}$ are, respectively, the number of nitrogen atoms in the N/Cu system and the difference in the number of Cu atoms between the N/Cu system and the clean surface slab. $E_{N/Cu}$ is the total energy of the N/Cu system, $E_{Cu}^{slab}$ the energy of the clean slab, $E_{Cu}$ the energy of a Cu atom in bulk Cu, and $E_N$ the energy of a free nitrogen atom from a spin-polarized calculation. The term $\Delta N_{Cu} E_{Cu}$ is only required when the total number of Cu atoms on the surface is different from that of the clean substrate, as is the case for Cu (110) surface reconstructions and the surface nitride structures on both Cu (110) and Cu (111). A positive binding energy indicates that the adsorption is exothermic, and a larger binding energy indicates a more stable structure.

Using concepts from “ab initio” atomistic thermodynamics,\textsuperscript{44,45} we determine the relative stability of the considered structures over a range of chemical potentials for the nitrogen atom. In particular, we calculate the Gibbs free energy of adsorption,

$$\Delta G(T,p) = \frac{1}{2A}(G_{N/Cu} - G_{Cu}^{slab} - \Delta N_{Cu} \mu_{Cu} - N_N \mu_N),$$

where $G_{N/Cu}$ and $G_{Cu}^{slab}$ are the Gibbs free energies of the N/Cu system and the clean surface, respectively. $A$ is the surface area of the N/Cu structure, and $\mu_N$ and $\mu_{Cu}$ are the chemical potentials of the nitrogen and copper atoms. The term $\Delta N_{Cu} \mu_{Cu}$ represents the cost of interchanging the Cu species with a reservoir of Cu atoms with chemical potential $\mu_{Cu}$. This reservoir is taken to be bulk Cu, with which the surface is assumed to be in equilibrium. For more details, we refer to Refs. 44 and 45. By incorporating Eq. (1) into Eq. (2), we simplify Eq. (2) to give

$$\Delta G(\Delta \mu_N) = \frac{1}{2A}(-N_N E_N^N - N_N \Delta \mu_N),$$

where the nitrogen chemical potential is now measured with respect to the free nitrogen atom, $\Delta \mu_N = \mu_N - E_N$, and we neglect contributions due to vibrations and the pressure-volume term.\textsuperscript{44}
III. RESULTS AND DISCUSSION

A. Cu (100) and Cu (110) surfaces, bulk Cu, and the N₂ molecule

The properties of bulk Cu, clean Cu surfaces, and the N₂ molecule are first considered to ensure that the DFT calculations provide accurate results. The properties of these systems are well known from experimental results as well as from other ab initio calculations.

The calculated lattice constant of bulk Cu (neglecting zero-point vibrations) is 3.64 Å, which is in good agreement with the established experimental value of 3.61 Å. The Brillouin-zone integration for bulk Cu is performed using a (12×12×12) Monkhorst-Pack grid for a (1×1×1) conventional cell with real-space radius cutoff of 9 bohrs. The computed bulk modulus and cohesive energy (taking into account the spin-polarization energy for the free Cu atom) are 136 GPa and 3.45 eV, which are in excellent agreement with the experimental values of 137 GPa and 3.49 eV, respectively. The minor overestimation of the lattice constant and the underestimate of the bulk modulus are also observed in analogous studies of other transition metals.

For the clean Cu (100) surface, the obtained interlayer relaxations \( \Delta_{ij} = (d_{ij} - d) / d \times 100\% \) between layers \( i \) and \( j \), with respect to the bulk spacing \( d = 1.82 \) Å, are \( \Delta_{23} = -2.3\% \) and \( \Delta_{23} = 1.0\% \) for the topmost layers. These results correlate well with other PAW-GGA DFT calculations, with \( \Delta_{23} = -2.6\% \) and \( \Delta_{23} = 0.9\% \) and experimental LEED data, with \( \Delta_{23} = -2.1\% \) and \( \Delta_{23} = 0.5\% \). The calculated work function for the clean surface is 4.39 eV, which is similar to the reported experimental value of 4.59 eV (Ref. 52) and theoretical value of 4.49 eV (Ref. 17). We note that it is typical that DFT-GGA calculations slightly underestimate the work function of metal surfaces. The surface energy is calculated to be 0.64 eV per surface unit cell (or 1.5 J m⁻²), which is in good agreement with DFT-GGA calculations using the full-potential linearized augmented-plane-wave (FP-LAPW) method, where a value of 0.60 eV is reported. Our calculated surface energy is found to be much lower than the only reported experimental value (5.5 J m⁻² or 0.34 eV Å⁻²) but is in line with the theoretical value reported above.

Considering the clean Cu (110) surface, the obtained interlayer relaxations are \( \Delta_{12} = -10.0\% \) and \( \Delta_{23} = 3.0\% \). These results agree with experimental values with \( \Delta_{12} = -10.0\% \pm 2.5\% \) and \( \Delta_{23} = 0.0\% \pm 2.5\% \), and reasonably well with theoretical results using the FP-LAPW method, yielding \( \Delta_{12} = -9.7\% \) and \( \Delta_{23} = 3.6\% \). The work function for the clean surface is calculated to be 4.18 eV, which is in reasonable agreement with the reported experimental value of 4.48 eV. Using the tight-binding linear muffin-tin orbital (TB-LMTO) approach and the local density approximation (LDA), the work function of Cu (110) was found to be 4.80 eV, which is higher than our calculated value. This is typical of LDA-derived work functions of metals which are generally larger than those calculated with the GGA. The surface energy is calculated to be 0.97 eV per surface unit cell, which correlates well with the DFT-GGA (FP-LAPW) (Ref. 54) value of 0.901 eV. To the best of our knowledge, we did not find the corresponding experimental surface energy value for Cu (110).

Spin-unrestricted calculations using nonspherical densities are performed to study the nitrogen atom and molecule. To achieve high numerical accuracy, the real-space cutoff for the calculation is increased to 20 bohrs, with the largest basis set available in the DMol³ code. The binding energy of N₂ per N atom is calculated to be 5.19 eV, which is typically overbound when compared to the reported experimental value of 4.90 eV. The bond length and vibrational frequency are 1.11 Å and 2349.6 cm⁻¹, respectively, which compare very well with the reported experimental values of 1.10 Å and 2358.6 cm⁻¹.

B. Binding energy and structural parameters

1. Nitrogen adsorption on Cu (100)

For the Cu (100) surface, chemisorption structures with coverages of 0.125, 0.25, 0.5, 0.75, and 1 ML are investigated. It is observed that the binding energy increases from 4.50 to 4.76 eV for coverages of 0.125–0.5 ML and thereafter decreases to 3.40 eV at 1 ML, as shown in Fig. 2(a). Typically, on-surface adsorption of electronegative adsorbates on a metal surface leads to a decreasing binding energy with increasing coverage, which is due to a repulsive interaction between these electronegative atoms at close distances (i.e., high coverages). Our binding energy trend deviates from this, implying that the internitrogen interaction on Cu (100) is attractive at 0.5 ML coverage. This is consistent with the observed island formation with a local N coverage of 0.5 ML, with a Cu (100)-(c(2×2))-N local structure. As the coverage of nitrogen is increased, the size of the islands increases, forming a uniform Cu (100)-(c(2×2))-N structure at saturation.

In the relaxed structures at coverages of 0.75 and 1 ML on Cu (100), the N atoms are not all positioned above the surface Cu layer. At 0.75 ML coverage, the relaxed structure consists of two N atoms situated above the Cu substrate and one situated below the top layer, while at a coverage of 1 ML, all N atoms are positioned 0.47 Å below the Cu surface layer. These structures have a low binding energy, compared to the low-coverage adsorption phases, with binding energies of only 3.74 eV and 3.40 eV, for the 0.75-ML and 1-ML structures, respectively. A second 1-ML N/Cu (100) structure was examined, with the N atoms initially positioned 0.65 Å above the surface, compared to 0.21 Å for the initial 0.75-ML and 1-ML structures. The relaxed (metastable) structure has all N atoms 0.49 Å above the surface, with a binding energy of 3.01 eV, which is lower than the binding energy for 1 ML coverage in the subsurface sites. The preference for the subsurface site, compared to the on-surface site, could be due to the additional coordination of the N atom to the Cu atoms in the second layer and a consequent more effective screening of the partially charged and closely positioned N atoms.

To correlate the binding energy trend with surface geometry, we examine the structural properties of N adsorbed on Cu. Table I lists average bond lengths between adsorbed N and Cu atoms and the interlayer spacings between the outer...
Cu layers. A shorter Cu-N bond length is indicative of a stronger Cu-N bond and thus may indicate a more stable structure. The bond length $d_{\text{Cu-N}}$ for the Cu (100)-(c(2 × 2)-N structure is 0.09 Å smaller than $d_{\text{Cu-N}}$ for Cu (100)-(p(2 × 2)-N, which correlates well with the binding energy calculations, as the Cu (100)-(c(2 × 2)-N structure is 0.24 eV more favorable than the Cu (100)-(p(2 × 2)-N structure. Also, in Table I, it is seen that the interlayer distance $d_{12}$ increases from 1.81 Å at 0.125 ML to 2.25 Å at a full ML on-surface coverage, whereas $d_{23}$ remains almost constant (~1.82 Å) for all considered coverages of N. The large variation in $d_{12}$ reflects the stronger Cu-Cu bonds formed on the Cu (100) surface which weaken the Cu-Cu bonds of the first layer Cu atoms to the underlying Cu atoms in the substrate and hence explains the almost constant value of $d_{23}$. Overall, our calculated structural parameters compare well with another DFT study of the Cu (100)-(c(2 × 2)-N phase, which determined the Cu-N bond length to be 1.83 Å and $d_{\text{N1}}=0.20$ Å, and an experimental study, which reported $d_{\text{Cu-N}}=1.85$ Å.

2. Nitrogen adsorption on Cu (110)

The Cu (110) surface reconstruction adsorption phases studied included (i) a surface nitridelike structure Cu (110)-(p(2 × 3)-4N (\(\Theta_N=0.66\) ML) [Fig. 1(e)], (ii) nitrogen adsorption in the LB site on the [001] missing-row Cu (110) surface Cu (110)-(p(2 × 3)-2N (\(\Theta_N=0.33\) ML) [Fig. 1(e)], and (iii) nitrogen chemisorption on the [110] missing-row Cu (110) surface in the LB site, Cu (110)-(p(2 × 3)-N (\(\Theta_N=0.17\) ML) [Fig. 1(d)]. We also investigate nitrogen adsorption at the SB, 4FH, and 3FH (pseudo-threefold-hollow) sites at a low coverage of \(1/4\) ML. In addition, chemisorption on an unreconstructed Cu (110) surface is studied in the SB site at 0.25 ML coverage, in the LB site from 0.125 to 0.5 ML, and in the 4FH hollow site from 0.125 to 1 ML.

From Fig. 2(b), it can be seen that the surface nitride structure Cu (110)-(p(2 × 3)-4N has the most favorable binding energy for all considered Cu (110) adsorption phases, having an average binding energy of 4.71 eV. After this, the Cu (110)-(p(2 × 3)-2N structure is the next most favorable, with a binding energy of 4.33 eV, while the Cu (110)-(p(2 × 3)-N structure on the [110] missing-row surface has a binding energy of 3.79 eV. The latter structure is not the most energetically favored structure on the [110] missing-row surface. The most favorable site for N on the [110] missing-row surface is where N is in the 4FH site—i.e., fourfold coordinated to the surface Cu atoms and onefold coordinated to the Cu directly below in the second substrate layer (\(\Theta_N=0.17\) ML), which has a binding energy of 4.00 eV [not shown in Fig. 2(b)].

For chemisorption on the unreconstructed Cu (110) surface, the most favorable adsorption site at 0.25 ML coverage is the 4FH site, with a binding energy of 4.13 eV, compared to 3.97 eV at the LB site and 3.03 eV at the SB site (not shown). For N adsorption at the 4FH site, the binding energy decreases with increasing coverage, while for that at the LB site, the binding energy plateaus with increasing coverage. For coverages below 0.25 ML, the 4FH site is favored over the LB site. However, as the coverage increases above ~0.3 ML, the LB site becomes preferred over the 4FH site.

From Table II it can be seen that, unlike for N/Cu (100), the trend in binding energy for N/Cu (110) surface reconstructions is not reflected in the Cu-N bond lengths. In particular, the Cu-N bond length for the most favorable Cu (110)-(p(2 × 3)-4N structure is actually about 0.5% longer than that of the less favorable Cu (110) surface reconstructions that we have considered. However, the observed $d_{\text{Cu-N}}$ for Cu (110)-(p(2 × 3)-4N is only 0.02 Å smaller than the Cu-N bond length of bulk copper nitride and the atomic structure of the surface nitride closely resembles the structure of bulk copper nitride. This suggests that the Cu (110)-(p(2 × 3)-4N structure may be a precursor to the formation of the bulk copper nitride phase. In addition, due to the favoring of these more complex surface nitridelike structures, the interlayer distances $d_{12}$ and $d_{23}$ do not correlate with increasing N coverage. Overall, $d_{12}$ remains fairly constant, with the exception of Cu (110)-(p(2 × 3)-4N and Cu (110)-(p(2 × 4)-N having a contraction of 3.8% and 6.2%, respectively. On the other hand, unlike for N/Cu (100), $d_{23}$ does not remain a
TABLE II. Calculated geometric structural parameters (in Å) for different surface structures at nitrogen coverages \( \Theta \) and the N binding energy \( E_{\text{N/Cu}} \) (in eV) with respect to the free nitrogen atom. \( d_{\text{Cu-N}} \) indicates the average bond length between nitrogen and the nearest copper atom. \( d_{\text{N}} \) is the planar averaged vertical height of N above the topmost Cu layer. For the surface reconstructions and surface nitrides, \( d_{\text{N}} \) is defined to be the distance between the middle of the surface nitride layer and the first layer of unconstructed Cu atoms. \( d_{\text{N}} \) is defined to be the largest positive vertical displacement between a N atom and the topmost Cu layer. The computed bulk Cu interlayer spacing is 1.30 Å for Cu (110) and 2.10 Å for Cu (111), and \( d_{\text{Cu,N}} \) in bulk Cu,N is 1.92 Å. Nitrogen coverage \( \Theta \) (in ML) for each structure is shown in brackets.

<table>
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<th>Structure</th>
<th>Cu (110)-(2×3)-N (0.17 ML)</th>
<th>Cu (110)-(2×3)-2N (0.33 ML)</th>
<th>Cu (110)-(2×3)-4N (0.66 ML)</th>
<th>Cu (110)-(2×4)-N (0.125 ML)</th>
<th>N/Cu (111) &quot;16&quot; (0.44 ML)</th>
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<td>( d_{\text{N}} )</td>
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<td>—</td>
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<td>—</td>
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<tr>
<td>( d_{12} )</td>
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<td>1.25</td>
<td>1.22</td>
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<tr>
<td>( d_{23} )</td>
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constant with varying N coverage. A small contraction of 1.5% is observed for both Cu (110)-(2×3)-2N and Cu (110)-(2×3)-4N, while a larger contraction of 7.7% is seen for Cu (110)-(2×3)-N and an expansion of 2.3% for Cu (110)-(2×4)-N.

3. Nitrogen adsorption on Cu (111)

Our previous study\(^{39}\) examined N adsorption on Cu (111) in the fcc and hcp threefold hollow sites for coverages ranging from 0.125 to 1 ML. The experimentally observed surface nitride structure was modeled through both a “4” and a “16” reconstructed structure [Figs. 1(g)–1(i)]. The most favorable geometry was found to be the “16” reconstruction, shown in Figs. 1(g) and 1(h), which has an average binding energy per N atom of 4.35 eV at \( \frac{1}{16} \) ML coverage [see Fig. 2(c)]. For further details we refer to Ref. 39.

4. Comparison of nitrogen adsorption on Cu (100), (110), and (111)

This study has found that the most energetically favored nitrogen adsorption phase on Cu (100) is the Cu (100)-(c(2×2)-N) structure, while on Cu (110), the experimentally observed surface nitride Cu (110)-(p(2×3)) is the most preferred. For Cu (111), the surface nitride “16” structure is found to have the most favorable binding energy, compared to the other surface nitride and chemisorption structures considered on the (111) surface of Cu. Evidently, from Fig. 2, the Cu (100)-(c(2×2)) structure has the most favorable binding energy of all considered N/Cu low-index surface structures. We attribute the relative stability of these surface structures in terms of an interplay of two contributions to the nitrogen binding energy: (i) the average strain of the structures considered relative to the N-Cu-N bonds in bulk Cu,N and (ii) the energy cost of forming these N/Cu reconstruction structures: The average strain is calculated by taking the difference (in percent) between the horizontal distance (parallel to the surface) spanned by N-Cu-N bonds in the Cu (100)-(c(2×2)) and surface nitride structures and the distance spanned by N-Cu-N bonds of bulk Cu,N. This results in a strain of ~5.3%, ~1.65%, and ~5.20% for the Cu(100)-(c(2×2)), Cu (110)-(p(2×3)), and “16” structures, respectively. The Cu (110)-(p(2×3)) structure has the lowest strain, and if one only considers the strain, one would expect this to be the most favorable structure. However, the energy cost of reconstructing the Cu (110) and Cu (111) surfaces into the pseudo-Cu-(110)-like structure for N adsorption in a surface nitride phase also contributes significantly to the overall binding energy of these structures. For Cu (100), there is also an energy cost in the relaxation of Cu atoms into the same atomic positions as that in the Cu (100)-(c(2×2)) phase. We calculate the energy cost per nitrogen atom, \( E_{\text{cost}} \), as follows:

\[
E_{\text{cost}} = \frac{1}{N_N} \left[ E_{\text{Cu}}^{\text{relax}} - (E_{\text{Cu}}^{\text{ideal}} - \Delta N_{\text{Cu}} E_{\text{Cu}}) \right],
\]

where \( N_N \) is the number of nitrogen atoms in the corresponding N/Cu system, \( E_{\text{Cu}}^{\text{relax}} \) is the total energy of the reconstructed copper slab (without N) having the same fixed atomic positions as the N/Cu system, \( E_{\text{Cu}}^{\text{ideal}} \) is the energy of an ideal, relaxed copper slab, without any reconstruction, \( \Delta N_{\text{Cu}} \) is the difference in the number of Cu atoms between the reconstructed Cu surface and the ideal Cu surface (i.e., considering a symmetric slab with two identical surfaces exposed), and \( E_{\text{Cu}} \) is the energy of a single Cu atom in bulk Cu.

The calculated value of \( E_{\text{cost}} \) is 0.14, 0.57, and 0.78 eV for the Cu (100)-(c(2×2)), Cu (110)-(p(2×3)), and “16” structures, respectively. The energy cost in forming the Cu (100)-(c(2×2)) structure is much lower than that of the surface nitride structures on Cu (110) and Cu (111) because the Cu (100)-(c(2×2)) structure is formed by simple chemisorption and requires minimal relaxation of surface Cu atoms, while for the Cu (110) and Cu (111) surface nitride structures, Cu atoms are strongly displaced from their original position on the clean Cu surface (i.e., added to and removed from the ideal Cu substrate, respectively, for Cu (110) and Cu (111)). Thus, despite having the highest strain com-
pared to the surface nitride structures, it costs the Cu (100)-c(2 × 2)-N phase the least energy to form this surface atomic configuration, and enough energy is gained from N adsorption to become the most energetically favored N/Cu surface structure. The “16” structure is the least favorable structure, as it has the largest $E_{\text{cost}}$ compared to the other structures, possibly due to the stability of the clean Cu (111) surface.

Equation (4) is also used to determine the distortion energy of the Cu (100) surface, which is of interest because of the subsurface positions of N atoms in the relaxed adsorption phases at the high coverages of 0.75 and 1 ML. $E_{\text{cost}}$ is calculated to be 0.40 and 0.45 eV for the 0.75-ML and 1-ML structures, respectively. This in part is responsible for the notably smaller binding energies as compared to the lower-coverage structures. The other factor contributing to the weak binding of N in the 0.75-ML and 1.0-ML structures is the repulsive interaction between the closely situated and partially negatively charged N atoms.

C. Electronic properties

The electronic structure of N adsorbates on Cu is now presented. The calculated change in work function ($\Delta \Phi$), with respect to the clean Cu surface, and N-induced surface dipole moment ($\mu$) as a function of coverage for the low-index surfaces are displayed in Fig. 3. The work function is defined to be the difference between the electrostatic potential in the vacuum and the Fermi energy of the slab. The surface dipole moment $\mu$ (in Debye) is evaluated by the Helmholtz equation

$$\mu = \frac{A \Delta \Phi}{12 \pi \Theta},$$

where $A$ is the area in Å$^2$ per (1 × 1) surface unit cell, $\Delta \Phi$ is the work-function change in eV, and $\Theta$ is the coverage in monolayers.

The surface dipole moment is found to decrease with increasing coverage for the Cu (100) and Cu (110) structures. This behavior can be understood by considering the electron transfer process between adsorbate and substrate atoms: There is a substantial electronegativity difference between N and Cu (3.04−1.90=1.14), so electrons are transferred (or part thereof) from the Cu to N atoms. However, with increasing coverage, there will be a repulsive interaction between the partially negatively charged N atoms. To counter this repulsion, there will be a partial charge transfer of electron density back to the substrate, thus decreasing the surface dipole moment. The surface dipole moment is negative for the 1-ML Cu (100) subsurface structure, due to the position of the electronegative N atoms below the Cu surface. This results in a net positive charge at the surface and hence an outward-pointing, negative dipole moment.

For electronegative adsorbates, $\Delta \Phi$ typically increases with coverage, as more effective negative charges are added to the surface. This is observed in the Cu (100) chemisorption phases, where $\Delta \Phi$ increases from 0.29 eV at 0.125 ML to 1.96 eV for 1 ML coverage of N, positioned above the surface. The sharp drop in $\Delta \Phi$ for the 1-ML Cu (100) surf-

FIG. 3. (Color online) Calculated (a) surface dipole moment ($\mu$) and (b) work-function change ($\Delta \Phi$) relative to the clean Cu surface as a function of coverage for N adsorption at the 4FH site on the Cu (100) (shown as open-circle data points) and Cu (110) (shown as open-square data points) surfaces. The diamond-shaped data points labeled as “Cu (110) [recon.]” represent the following structures: Cu (110)-p(2 × 3)-N at 0.17 ML, Cu (110)-p(2 × 3)-2N at 0.33 ML, and Cu (110)-p(2 × 3)-4N at 0.66 ML. Cu (100)-p(1 × 1)-N$_8$ is the full monolayer N/Cu (100) structure with nitrogen atoms adsorbed on the surface in the 4FH site.

surface structure is due to the position of N below the surface. From Eq. (5), it is clear that a negative surface dipole moment results in a negative-work function change. The 0.5-ML-coverage structure Cu (100)-c(2 × 2)-N has a slightly lower work-function change compared to the 0.25-ML structure on Cu (100). This may be attributed to screening effects: the N atom in the Cu (100)-c(2 × 2)-N structure is positioned 0.21 Å above the surface Cu layer, while N in the Cu (100)-p(2 × 2)-N structure is 0.48 Å above the surface Cu layer. Hence, the contributions to $\Delta \Phi$ from the N atoms may be reduced due to a more efficient screening from the Cu atoms in the Cu (100)-c(2 × 2)-N structure.

Utilizing the simple relation that the surface dipole $\mu$ is proportional to the product of the averaged vertical distance of N (i.e., $d_{N1}$) from the substrate and the effective electronic charge on N, $Q_N$, we can estimate the surface dipole moment. $Q_N$ is estimated from the Mulliken population partition method. This form of charge population analysis, although not an absolute measure of the exact charge distribution, does provide a consistent measure of relative electronic charge (re)distribution. The average height of the N atom with respect to the top Cu layer, $d_{N1}$, for the Cu (100)-c(2 × 2)-N and Cu (100)-p(2 × 2)-N structures is 0.21 and 0.48 Å, respectively. Their corresponding $Q_N$ values are 0.74e and 0.65e. Thus, for Cu (100)-c(2 × 2)-N, the product is $d_{N1}Q_N=0.16e$ Å and that for Cu (100)-p(2 × 2)-N is 0.31e Å. From this simple analysis, one can then
easily see why Cu (100)-c(2×2)-N has a lower workfunction change compared to Cu (100)-p(2×2)-N.

The trend in work-function change for N chemisorption in the 4FH site of the unreconstructed Cu (110) surface increases with coverage, similar to the chemisorption phase on Cu (100). For the reconstruction phases, the Cu (110)-p(2×3)-2N and Cu (110)-p(2×3)-4N structures, corresponding to coverages of 0.33 ML and 0.66 ML, respectively, have almost identical work functions.

The ΔΦ trend for the reconstructed N/Cu (110) structures can be understood again by calculating the estimated surface dipole moment using the effective electronic charges on N in these two structures and the average height of the N atom with respect to the top Cu layer, \(d_{N1}\): for the Cu (110)-p(2×3)-2N structure, \(d_{N1}=0.11\) Å, and for Cu (110)-p(2×3)-4N, \(d_{N1}=0.13\) Å, i.e., they are comparable. However, the Cu (110)-p(2×3)-4N structure experiences greater screening effects due to the higher coordination of N atoms in this structure: N is bonded to four surface Cu atoms in the Cu (110)-p(2×3)-4N structure, while N is bonded to two surface Cu atoms in the Cu (110)-p(2×2)-2N structure. The resulting values of \(Q_N\) are 0.73e and 0.67e, respectively. This results in Cu (110)-p(2×3)-2N having a value of \(d_{N1}Q_N=0.07e\) Å and Cu (110)-p(2×3)-4N a value of 0.09e Å, and this correlates well with the actual DFT-calculated surface dipole moments.

The difference electron density distributions for selected N/Cu (100) and surface nitride phases, in planes perpendicular to the surface along the N-Cu bond, are presented in Fig. 4. These quantities are calculated as

\[
n^N(r) - n^{NCu}(r) = \rho(r) - n^N(r).
\]

Here \(n^{NCu}\) is the total electron density of the substrate/adsorbate system, from which the electron density of both the clean surface, \(n^Cu\), and that of the corresponding isolated nitrogen adlayer, \(n^N\), are subtracted. The positions of the pure Cu surface and nitrogen atoms are taken to be the ones of the relaxed adsorbate system and are kept fixed.

For the selected N/Cu surface structures shown in Fig. 4, we note some similarities: The nitrogen atoms appear to be almost coplanar with the adjacent Cu atoms. The electron densities of the nearest-neighbor Cu atoms are depleted (depicted as dotted lines in Fig. 4), while the electron densities of N atoms are enhanced (depicted as solid lines in Fig. 4). This can be attributed to the large electronegativity of N. The accumulation of electron density on the vacuum side of the surface for N results in an inward pointing surface dipole moment and a positive ΔΦ. The impact of the N atoms on its neighboring Cu atoms can also be seen to extend to the second Cu substrate layer. In particular, for the surface nitride reconstructions, there are N atoms which affect Cu atoms in the reconstructed layer as well as in the first layer of the unreconstructed slab.

To illustrate the difference in surface dipole moment observed for subsurface N/Cu (100) adsorption phase (at 1 ML) Cu (100)-p(1×1)-N\(_SS\) and the corresponding on-surface adsorption phase Cu (100)-p(1×1)-N\(_S\), their respective difference electron density distributions are shown in Figs. 4(a) and 4(b). The electron density for Cu (100)-p(1×1)N\(_S\) resembles that of the Cu (100)-c(2×2)-N structure. However, for Cu (100)-p(1×1)-N\(_SS\), it is clear that the electron density enhancement of the N atoms is concentrated below the Cu surface, thus leading to the outward-pointing surface dipole moment and negative ΔΦ. Furthermore, from the depleted electron density of the neighboring surface and second-layer Cu atoms, it is clear that N in this structure not only interacts and bonds to Cu atoms on the surface, but also with Cu atoms below the surface.

The projected densities-of-states (PDOS) are presented in Figs. 5 and 6. In Fig. 5, for the 0.5 ML Cu (100)-c(2×2)-N structure, single particle wave functions are also plotted at the \(\Gamma\) point for various different energy eigenvalues. In all cases, we observe a renormalization of the N 2p energy levels to lower energies and a hybridization between N 2p and Cu 3d states in the region from –8 to –4 eV. The PDOS for the Cu (100)-c(2×2)-N structure in Fig. 5 bears some resemblance to the PDOS corresponding to bulk Cu–N [see Fig. 9(a) of Ref. 39]; however, there is a noticeable peak at around –4 eV, which is absent from the PDOS corresponding to the bulk structure. Plotting the spatial distribution of the single-particle wave function at this eigenstate shows that this peak is due to weak N-Cu and strong Cu-Cu bonding.
states. Other features of Fig. 5 include a higher occupancy of hybridized N 2p and Cu 3d bonding states, than antibonding states, suggesting a stronger Cu-N bonding character in this structure than the cohesive energy of the metastable bulk nitride material (which is the case, i.e., of −4.76 eV versus −4.03 eV). The nature of the states in the PDOS is confirmed by the single-particle wave functions at chosen eigenstates at the Γ point, showing distinctly that the eigenvalues corresponding to low energies are due to bonding states, while those close to the Fermi level are due to antibonding states. Furthermore, the PDOS due to subsurface Cu 3d states is broader than that due to Cu 3d states from surface Cu atoms (Cu₃), and this is due to reduced coordination at the surface of the latter. The location of the peaks of the Cu (100)-c(2×2)-N PDOS corresponds well with another theoretical result obtained by the full potential linearized muffin-tin orbital (FP-LMTO) method.⁶¹

Figure 6 displays the PDOS for the following surface nitride and N/Cu (110) adsorption phases: Cu (110)-p(2×3)-4N, Cu (110)-p(2×3)-N, Cu (110)-p(2×3)-2N, and Cu (110)-p(2×4)-N₄FH (i.e., with N at the 4FH site). We see that the PDOS can be roughly partitioned into three sections: from −8 to −4 eV, bonding states between N 2p and Cu 3d; from −4 to −2 eV, dominantly Cu 3d nonbonding states; and antibonding states between N 2p and Cu 3d at −2 to 2 eV above the Fermi level. Similar to what is seen in Fig. 5, there is a renormalization of the N 2p energy levels to lower energies and a hybridization between N 2p and Cu 3d states in the region −8 to −4 eV. However, for Figs. 6(d)–6(f), the hybridization of the bonding states is less pronounced (see between −7 and −5 eV) than for the subsurface Cu states (Cu₃) and this is again due to reduced coordination of surface Cu atoms. It can be observed that the superposition of Cu₃ and Cu₃ states in Figs. 6(b)–6(f) leads to two dominant peaks, at energy values similar to the dominant peaks in the PDOS of Cu₃N, at around −3.8 and −2.5 eV [see Fig. 9(a) in Ref. 39].

A comparison of the PDOS due to the Cu (111) “16” structure [see Figs. 9(b) and 9(c) in Ref. 39] with the PDOS for Cu (100)-c(2×2)-N and Cu (110)-p(2×3)-4N shows peaks in similar positions (at around −3.8, −2.5, and −1.8 eV). The overall close resemblance of the PDOS for all the reconstructed models and the Cu (100)-c(2×2)-N structure to the bulk nitride is an indication that these surface nitrides and N chemisorption on Cu (100) could be a precursor phase before onset of the formation of the bulk material. For details of the PDOS of N/Cu (111) structures and Cu₃N, we refer the reader to Ref. 39.

D. Relative stability and nanoparticle morphology

In Fig. 7 we show the Gibbs-surface free energy of adsorption for the various structures considered. The nitrogen chemical potential at which bulk Cu₃N forms corresponds to the heat of formation of bulk Cu₃N (relative to the free N atom). The heat of formation of bulk Cu₃N per nitrogen atom is calculated as

![FIG. 5.](image1) (Color online) Projected density of states for the Cu (100)-c(2×2)-N structure. The dark, solid (blue) line represents the 3d states of Cu atoms in the top-layer Cu (i.e., Cu₃) and the pale, solid (green) line represents the second-layer Cu (i.e., Cu₃) 3d states, and the dotted (red) line represents N 2p states. The insets (i.e., left and right panels) show the spatial distribution of the wave function at the Γ point for the eigenstates indicated by the arrows. The positions of the atoms are indicated by small black dots and labeled accordingly.

![FIG. 6.](image2) (Color online) Projected density of states for selected low-energy N/Cu (110) surface structures: Cu (110)-p(2×3)-4N for different sections [see Fig. 1(f)]: (a) section I, (b) section II, and (c) section III and (d) Cu (110)-p(2×3)-N, (e) Cu (110)-p(2×3)-2N, and (f) Cu (110)-p(2×4)-N₄FH. The dark (blue) solid lines represent Cu 3d states from surface Cu layer (Cu₃), the lighter (green) solid lines represent second-layer Cu (Cu₃) 3d states, and the dotted dark (red) lines represent N 2p states.
isolated N atom

dashed line.

From Fig. 7, it can be seen that at low N chemical potential, the clean surface is the preferred structure for all surface orientations. For N adsorption on Cu (100) [Fig. 7(a)], at $\Delta \mu_{\text{N}}=−4.76$ eV, the Cu (100)-c(2×2)-N phase becomes the most favorable structure for a narrow energy window, until the chemical potential reaches $−4.03$ eV, where bulk copper nitride is preferred. From Fig. 7(b) it can be seen that the Cu (110)-p(2×3)-4N structure becomes more favorable than the clean Cu (110) surface at $\Delta \mu_{\text{N}}=−4.71$ eV, and thereafter the bulk phase is most favorable. For N on the Cu (111) surface, the “16” structure forms on Cu (111) at $\Delta \mu_{\text{N}}=−4.34$ eV [as seen in Fig. 7(c)] and then finally to the bulk copper nitride structure at $\Delta \mu_{\text{N}}=−4.03$ eV.

The shape of a Cu nanoparticle under various nitrogen-atom chemical potentials can be determined using the Wulff construction, which yields an optimal crystal shape that minimizes the Gibbs-surface free energy (i.e., absolute Gibbs-surface free energy). Each facet consists of a surface adsorption phase, and the distance of the facet from the center of the crystal is determined by the surface energy of the adsorption phase. The Gibbs-surface free energy is calculated by

$$\gamma = -\frac{N_{\text{c}}E_{\text{c}}}{2A} - \frac{N_{\text{N}}\Delta \mu_{\text{N}}}{2A} + \gamma_{\text{clean}},$$

where $A$ is the surface area and $\gamma_{\text{clean}}$ is the surface free energy.
FIG. 8. (Color online) The surface free energy of the most favorable, adsorption structures considered on Cu (100), Cu (110), and Cu (111) is plotted in (a) as a function of the nitrogen-atom chemical potential $\mu_N$. The horizontal lines at low $\mu_N$ show the region where the clean Cu surfaces are the preferred structure. The bottom figure (b) is a magnification of the top figure (a), with insets depicting the predicted Cu nanoparticle shapes for selected values of $\mu_N$.

energy of the clean substrate. The program WINXMORPH was used to plot the crystal nanomorphology.\textsuperscript{54,65}

The results for all low-indexed orientations are shown in Fig. 8(a), as a function of the nitrogen-atom chemical potential $\Delta\mu_N$. In Fig. 8(b), we show the resulting particle nanomorphology for three selected values of $\Delta\mu_N$. It can be seen that at low $\Delta\mu_N$, the crystal shape is dominated by clean Cu (111) facets, which has the lowest Gibbs-surface free energy for this chemical potential region. As $\Delta\mu_N$ is increased to the range where the Cu (110) surface nitride structure and the chemisorption phase of N/Cu (100) form—for example, at $\Delta\mu_N=-4.6$ eV—the crystal shape now consists of facets of Cu (100)-c(2×2)-N, a small portion of Cu (110)-p(2×3)-4N, and clean Cu (111) facets. However, as the potential is increased to $\Delta\mu_N=−4.2$ eV, the polyhedron consists almost entirely of the surface nitride phases on Cu (100), with small areas of N/Cu (110) and N/Cu (111): namely, the Cu (100)-c(2×2)-N, Cu (110)-p(2×3)-4N, and N/Cu (111) “16” structures. Beyond $\Delta\mu_N=−4.03$ eV, the bulk copper nitride structure forms and thus we expect the crystal would consist of surfaces of bulk Cu$_3$N. The Wulff construction is clearly limited by the number of surfaces we have studied: inclusion of stepped surfaces, for example, may affect the predicted shape of the crystal. However, it is well known that the low-index faces are the most stable structures,\textsuperscript{66} so the basic predicted shape is not expected to change drastically.

IV. CONCLUSIONS

We performed density-functional-theory calculations to investigate the adsorption of nitrogen on the Cu (100) and Cu (110) surfaces. For chemisorption of N on Cu (100), the preferred adsorption phase is the 0.5-ML Cu (100)-c(2×2)-N structure, where adsorption is in the fourfold hollow sites, in agreement with experiment. For adsorption of N on Cu (110), in addition to adsorption on the unreconstructed substrate, various surface reconstructions, including a surface nitride reconstruction, were considered. The most stable adsorption phase was found to be the Cu (110)-p(2×3)-4N structure, where the surface reconstructs into a configuration which closely resembles that of a layer of bulk Cu$_3$N. Using the Gibbs-surface free energy and including the results of our previous investigation into N adsorption on Cu (111),\textsuperscript{39} we obtain the predicted Cu particle nanomorphology based on the Wulff construction. At low nitrogen chemical potential, the clean Cu (111) facets dominate the crystal shape, while just prior to the formation of bulk copper nitride surfaces, the Cu crystal is composed of only Cu (100)-c(2×2)-N and Cu (110)-p(2×3)-4N facets. Collectively, we find for all low-energy N/Cu surface structures—namely, Cu (100)-c(2×2)-N and the surface nitrides found on Cu (110) and Cu (111)—that they share a common geometric feature with surface nanopatterns resembling one atomic layer of Cu$_3$N(100). These structures are predicted to exist for a narrow range of nitrogen chemical potential before the onset of bulk Cu$_3$N formation, unless kinetically hindered. These observations are qualitatively very similar to the surface oxides found on transition-metal surfaces in an oxygen atmosphere (see Ref. 44 and references therein).

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APPENDIX

To test the accuracy of our calculated adsorption energies on a number of calculation parameters—namely, the real-space cutoff, the slab thickness, and the k-point grid to integrate the Brillouin zone—selected calculations have been repeated with higher accuracy. We find that none of these aspects qualitatively affect the conclusions made in this work as explained below.

First, for bulk Cu, by varying the real-space cutoff from 9 (as used in our studies) to 11 bohrs, the calculated cohesive energy of bulk copper did not differ by more than 1 meV per Cu atom. The same difference of 1 meV per Cu atom was also found for the calculated cohesive energy of bulk Cu when varying the k-point grid from 8×8×8 to 16×16×16. This demonstrates that the chosen real-space cutoff gives a good description of the bulk properties of Cu, which, is reported in detail in Ref. 45.
Next, we have tested the convergence of our slab calculations by testing the change in surface energy, \( \gamma_{\text{clean}} \) (in eV/\( \AA^2 \)), as a function of the \( k \)-point mesh. For example, in Table III, for Cu (100), increasing the \( k \)-point mesh from 8 \( \times \) 8 \( \times \) 1 to 14 \( \times \) 14 \( \times \) 1 does not change the surface energy by more than 5 meV/\( \AA^2 \) and the interlayer changes remain at most by 0.01%. Increasing from 12 \( \times \) 12 \( \times \) 1 (used in the present study) to 14 \( \times \) 14 \( \times \) 1 changes the two properties by at most 1 meV/\( \AA^2 \) and 0%.

For the Cu (110) surface, the change in surface energy and interlayer relaxations on increasing from 12 \( \times \) 6 \( \times \) 1 (used in the present study) to 14 \( \times \) 12 \( \times \) 1 are similarly at most 1 meV/\( \AA^2 \) and 0%.

### Table III. Comparison of surface energy \( \gamma_{\text{clean}} \) (in eV/\( \AA^2 \)) and interlayer distances—i.e., \( \Delta_{12} \) and \( \Delta_{23} \) (in %)—as a function of the \( k \)-point mesh for the clean Cu (100) and Cu (110) surfaces.

<table>
<thead>
<tr>
<th>Surface</th>
<th>( k )-point mesh</th>
<th>( \gamma_{\text{clean}} )</th>
<th>( \Delta_{12} )</th>
<th>( \Delta_{23} )</th>
</tr>
</thead>
<tbody>
<tr>
<td>Cu (100)</td>
<td>8 ( \times ) 8 ( \times ) 1</td>
<td>0.093</td>
<td>-2.5</td>
<td>0.77</td>
</tr>
<tr>
<td></td>
<td>12 ( \times ) 12 ( \times ) 1</td>
<td>0.097</td>
<td>-2.5</td>
<td>0.76</td>
</tr>
<tr>
<td></td>
<td>14 ( \times ) 14 ( \times ) 1</td>
<td>0.098</td>
<td>-2.5</td>
<td>0.76</td>
</tr>
<tr>
<td>Cu (110)</td>
<td>6 ( \times ) 3 ( \times ) 1</td>
<td>0.104</td>
<td>-8.7</td>
<td>1.4</td>
</tr>
<tr>
<td></td>
<td>12 ( \times ) 6 ( \times ) 1</td>
<td>0.103</td>
<td>-10.3</td>
<td>2.7</td>
</tr>
<tr>
<td></td>
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<td>-10.2</td>
<td>2.6</td>
</tr>
<tr>
<td></td>
<td>14 ( \times ) 12 ( \times ) 1</td>
<td>0.102</td>
<td>-10.3</td>
<td>2.7</td>
</tr>
</tbody>
</table>
73, 165424 (2006).